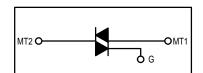
Triacs

Silicon Bidirectional Triode Thyristors

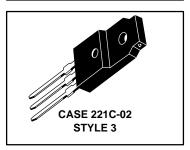
... designed primarily for full-wave ac control applications, such as lighting systems, heater controls, motor controls and power supplies; or wherever full-wave silicongate-controlled devices are needed.

- · Off-State Voltages to 800 Volts
- All Diffused and Glass Passivated Junctions for Parameter Uniformity and Stability
- Small, Rugged Thermowatt Construction for Thermal Resistance and High Heat Dissipation
- Gate Triggering Guaranteed in Three Modes (MAC223FP Series) or Four Modes (MAC223AFP Series)



MAC223FP Series MAC223AFP Series

ISOLATED TRIACS THYRISTORS 25 AMPERES RMS 200 thru 800 VOLTS



MAXIMUM RATINGS ($T_J = 25^{\circ}$ unless otherwise noted.)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage ⁽¹⁾ (T _J = -40 to +125°C, 1/2 Sine Wave 50 to 60 Hz, Gate Open) MAC223-4FP, MAC223A4FP MAC223-6FP, MAC223A6FP MAC223-8FP, MAC223A8FP	VDRM	200 400 600	Volts
MAC223-10FP, MAC223A10FP		800	
On-State RMS Current ($T_C = +80^{\circ}C$) Full Cycle Sine Wave 50 to 60 Hz(2)	I _T (RMS)	25	Amps
Peak Nonrepetitive Surge Current (One Full Cycle, 60 Hz, T _C = 80°C, preceded and followed by rated current)	ITSM	250	Amps
Circuit Fusing (t = 8.3 ms)	I ² t	260	A ² s
Peak Gate Power (t ≤ 2 μs)	PGM	20	Watts
Average Gate Power ($T_C = +80^{\circ}C$, $t \le 8.3 \text{ ms}$)	P _{G(AV)}	0.5	Watt
Peak Gate Current (t \leq 2 μ s)	I _{GM}	2	Amps
Peak Gate Voltage (t \leq 2 μ s)	Vgм	±10	Volts
RMS Isolation Voltage (T _A = 25°C, Relative Humidity ≤ 20%)	V(ISO)	1500	Volts
Operating Junction Temperature	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C
Mounting Torque		8	in. lb.

^{1.} V_{DRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	1.2	°C/W
Thermal Resistance, Case to Sink	$R_{\theta CS}$	2.2	°C/W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	60	°C/W



^{2.} The case temperature reference point for all T_C measurements is a point on the center lead of the package as close as possible to the plastic body.

MAC223FP Series MAC223AFP Series

ELECTRICAL CHARACTERISTICS (T_C = 25°C and either polarity of MT2 to MT1 voltage unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak Blocking Current ⁽¹⁾ $T_J = 25^{\circ}C$ $(V_D = Rated V_{DRM}, Gate Open)$ $T_J = 125^{\circ}C$	I _{DRM}	_		10 2	μA mA
Peak On-State Voltage (I _{TM} = 35 A Peak, Pulse Width ≤ 2 ms, Duty Cycle ≤ 2%)	V _{TM}	_	1.4	1.85	Volts
Gate Trigger Current (Continuous dc) $ (V_D=12\ V,\ R_L=100\ \Omega) \\ MT2(+),\ G(+);\ MT2(-),\ G(-);\ MT2(+),\ G(-) \\ MT2(-),\ G(+)\ "A"\ SUFFIX\ ONLY $	I _{GT}		20 30	50 75	mA
Gate Trigger Voltage (Continuous dc) $ (V_D = 12 \ V, \ R_L = 100 \ \Omega) $ $ MT2(+), \ G(+); \ MT2(-), \ G(-); \ MT(+), \ G(-) $ $ MT2(-), \ G(+) \ "A" \ SUFFIX \ ONLY $ $ (V_D = Rated \ V_{DRM}, \ T_J = 125^{\circ}C, \ R_L = 10 \ k) $ $ MT(+), \ G(+); \ MT2(-), \ G(-); \ MT2(+), \ G(-) $ $ MT2(-), \ G(+) \ "A" \ SUFFIX \ ONLY $	Vgт	 0.2 0.2	1.1 1.3 0.4 0.4	2 2.5 —	Volts
Holding Current (V _D = 12 V, I _{TM} = 200 mA, Gate Open)	lΗ	_	10	50	mA
Gate Controlled Turn-On Time (V _D = Rated V _{DRM} , I _{TM} = 35 A Peak, I _G = 200 mA)	^t gt	_	1.5	_	μѕ
Critical Rate of Rise of Off-State Voltage (V _D = Rated V _{DRM} , Exponential Waveform, T _C = 125°C)	dv/dt	_	40	_	V/µs
Critical Rate of Rise of Commutation Voltage (V_D = Rated V_{DRM} , I_{TM} = 35 A Peak, Commutating di/dt = 12.6 A/ms, Gate Unenergized, T_C = 80°C)	dv/dt(c)	_	5	_	V/µs

^{1.} Ratings apply for open gate conditions. Devices shall not be tested with a constant current source for blocking voltage such that the voltage applied exceeds the rated blocking voltage.

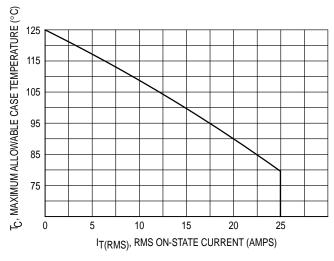


Figure 1. RMS Current Derating

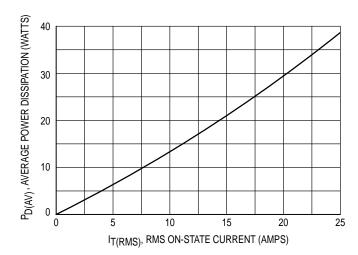


Figure 2. On-State Power Dissipation

MAC223FP Series MAC223AFP Series

TYPICAL CHARACTERISTICS

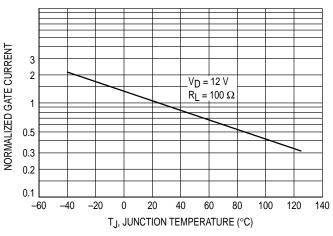


Figure 3. Gate Trigger Current

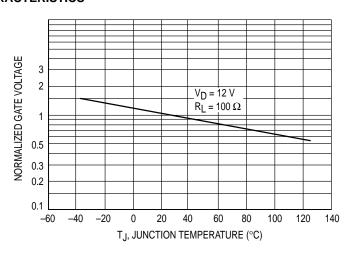


Figure 4. Gate Trigger Voltage

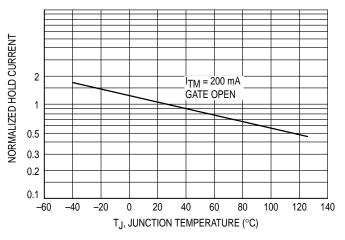


Figure 5. Hold Current

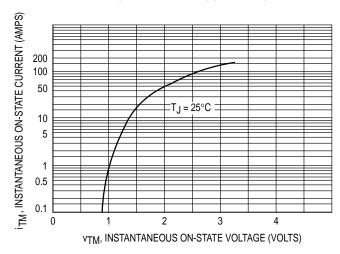
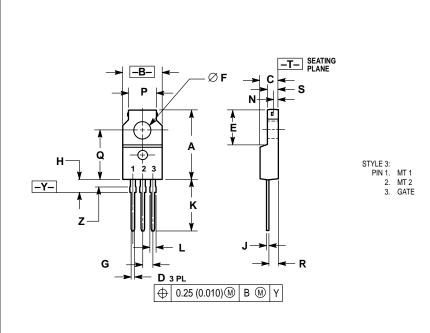


Figure 6. Typical On-State Characteristics

MAC223FP Series MAC223AFP Series

PACKAGE DIMENSIONS



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
 - 2 CONTROLLING DIMENSION: INCH
- 3. LEAD DIMENSIONS UNCONTROLLED WITHIN DIMENSION Z.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.680	0.700	17.28	17.78	
В	0.388	0.408	9.86	10.36	
С	0.175	0.195	4.45	4.95	
D	0.025	0.040	0.64	1.01	
Е	0.340	0.355	8.64	9.01	
F	0.140	0.150	3.56	3.81	
G	0.100 BSC		2.54 BSC		
Н	0.110	0.155	2.80	3.93	
J	0.018	0.028	0.46	0.71	
K	0.500	0.550	12.70	13.97	
L	0.045	0.070	1.15	1.77	
N	0.049		1.25		
Р	0.270	0.290	6.86	7.36	
Q	0.480	0.500	12.20	12.70	
R	0.090	0.120	2.29	3.04	
S	0.105	0.115	2.67	2.92	
Z	0.070	0.090	1.78	2.28	

CASE 221C-02

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MAC223FP/D